## **DIODE MODULE** (F.R.D.)

# **MDF(R)250A-L/M**







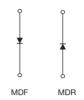
MDF(R)250A-L/M are high speed diode with flat mounting base which is designed for switching application of high power.

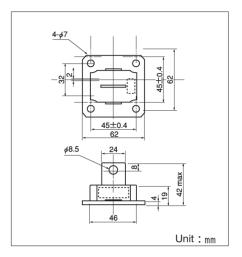
- IF(AV) 250A VRRM=400V
- Easy Construction with Anode (F) Type and Cathode (R) Type
- Reverse Recovery Time (trr) L Type: 450ns, M Type: 550ns
- High Reliability by Glass passivated Chips

(Applications)

Switching Power Supply.

Inverter Welding Power Supply





#### Maximum Ratings

Symbol	Itam	Ratings			
	Item	MDF(R)250A20L/M	MDF(R)250A30L/M	MDF(R)250A40L/M	Unit
VRRM	Repetitive Peak Reverse Voltage	200	300	400	V
VRSM	Non-Repetitive Peak Reverse Voltage	240	360	480	V
VR (DC)	D.C. Reverse Voltage	160	240	320	V

Symbol	Item		Conditions	Ratings	Unit
IF (AV)	Average Forward Current		Single phase, half wave, 180 conduction, Tc:L/M 83 /85 C	250	Α
IF (RSM)	R.M.S. Forward Current		Single phase, half wave, 180 conduction, Tc:L/M 83 /85 C	390	Α
IFSM	Surge Forward Current		1/2 cycle, 50/60Hz, peak value, non-repetitive	4000/4500	А
l²t	I²t		Value for one cycle of surge cureent	84000	A <sup>2</sup> S
Tj	Operating Junction Temperature			<del>-30</del> ∼+150	℃
Tstg	Storage Temperature			<b>−</b> 30∼ <b>+</b> 125	℃
	Mounting	Mounting (M6)	Recommended Value 2.5~3.9 (25~40)	4.7 (48)	N·m
	Torque	Terminal (M8)	Recommended Value 8.8~10 (90~105)	11 (115)	(kgf·cm)
	Mass		Typical Value	170	g

#### **■**Electrical Characteristics

Symbol	Item	Conditions		Ratings	Unit
IRRM	Repetitive Peak Reverse Current, max	at VDRM, single phase, half wave, Tj=150°C		60	mA
VFM	Forward Voltage Drop ,max	Foward current 800A, T <sub>j</sub> =25 ℃		1.4	V
		Inst, measurement	М	1.3	]
Rth (j-c)	Thermal Impedance,max	Junction to case		0.2	°C/W
trr	Reverse Recovery Time, max	$T_j=25$ °C, IF=2A, $di/dt=20A/\mu$ s	L	450	- ns
			М	550	

### **MDF(R)250A-L/M**







